# **DRD1010F60**



# **Rectifier Diode**

DS5984-1 January 2011(LN28005)

### **FEATURES**

- Double Side Cooling
- High Surge Capability

## **APPLICATIONS**

- Rectification
- Free-wheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages V <sub>DRM</sub> and V <sub>DRM</sub> V	Conditions
DRD1010F60 DRD1010F59 DRD1010F58 DRD1010F57 DRD1010F56 DRD1010F55	6000 5900 5800 5700 5600 5500	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.

## **KEY PARAMETERS**

$V_{RRM}$	6000V
I <sub>F(AV)</sub>	1015A
I <sub>FSM</sub>	16500A

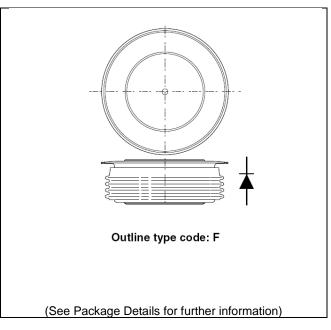


Fig. 1 Package outlines

# **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table, e.g.:

## DRD1010F59

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.



# **CURRENT RATINGS**

## $T_{\text{case}}$ = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	1320	А			
I <sub>F(RMS)</sub>	RMS value	-	2073	Α			
I <sub>F</sub>	Continuous (direct) on-state current	-	1897	Α			
Single Sig	Single Side Cooled (Anode side)						
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	947	А			
I <sub>F(RMS)</sub>	RMS value	-	1487	А			
I <sub>F</sub>	Continuous (direct) on-state current	-	1283	А			

## $T_{\text{case}}$ = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	1015	Α			
I <sub>F(RMS)</sub>	RMS value	-	1594	Α			
l <sub>F</sub>	Continuous (direct) on-state current	-	1480	Α			
Single Sid	de Cooled (Anode side)		•				
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	680	Α			
I <sub>F(RMS)</sub>	RMS value	-	1067	Α			
I <sub>F</sub>	Continuous (direct) on-state current	-	920	Α			



# **SURGE RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 150°C	13.5	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4}$ sine	0.92	MA <sup>2</sup> s
I <sub>FSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 150°C	16.5	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 0$	1.425	MA <sup>2</sup> s

## THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	DC	-	0.022	°C/W
		Single side cooled	Anode DC	-	0.038	°C/W
			Cathode DC	-	0.052	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Clamping force 19.5kN	Double side	-	0.004	°C/W
		(with mounting compound)	Single side	-	0.008	°C/W
$T_{vj}$	Virtual junction temperature	On-state (conducting)		-	160	°C
		Reverse (blocking)		-	150	°C
T <sub>stg</sub>	Storage temperature range			-55	175	°C
Fm	Clamping force			18.0	22.0	kN

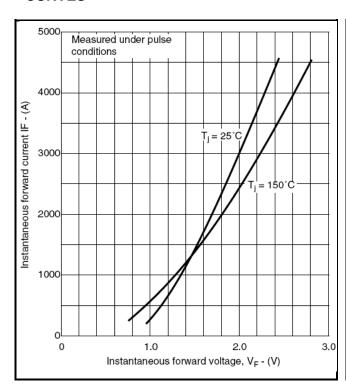
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### **CHARACTERISTICS**

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V <sub>FM</sub>	Forward voltage	At 3400A peak, T <sub>case</sub> = 25°C	-	2.1	V
I <sub>RM</sub>	Peak reverse current	At V <sub>DRM</sub> , T <sub>case</sub> = 150°C	-	75	mA
Qs	Total stored charge	I <sub>F</sub> = 2000A, dI <sub>RR</sub> /dt =3A/μs	-	4500	μC
I <sub>rr</sub>	Peak reverse recovery current	$T_{case} = 150^{\circ}C, V_{R} = 100V$	-	120	Α
V <sub>TO</sub>	Threshold voltage	At T <sub>vj</sub> = 150°C	-	1.0	V
r <sub>T</sub>	Slope resistance	At T <sub>vj</sub> = 150°C	-	0.42	mΩ

## **CURVES**



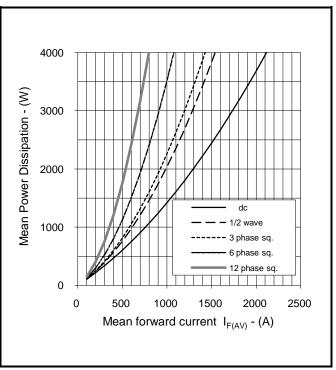


Fig.2 Maximum (limit) on-state characteristics

Fig.3 Dissipation curves

 $V_{\text{TM}}$  EQUATION

 $V_{TM} = A + Bln (I_T) + C.I_T + D.\sqrt{I_T}$ 

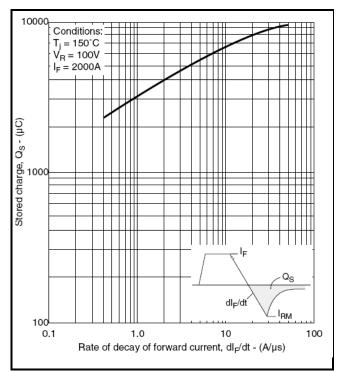
Where A = 0.819645

B = -0.13673

 $C = 5.73x10^{-5}$ 

D = 0.042435

these values are valid for  $T_j$  = 150 °C for  $I_F$  500A to 5000A





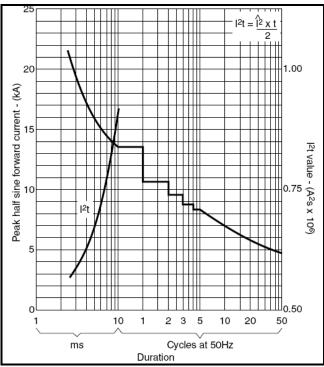


Fig.6 Surge (non-repetitive) forward current vs time (with 50% V<sub>RRM</sub> at T<sub>case</sub> 150°C)

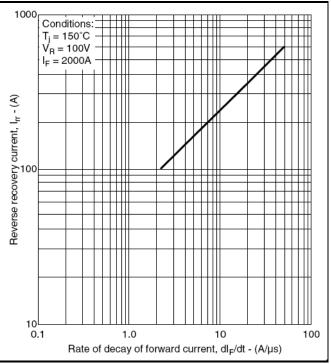


Fig.5 Maximum reverse recovery current

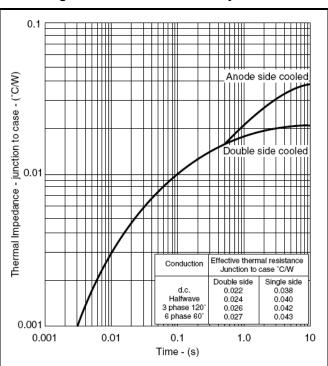
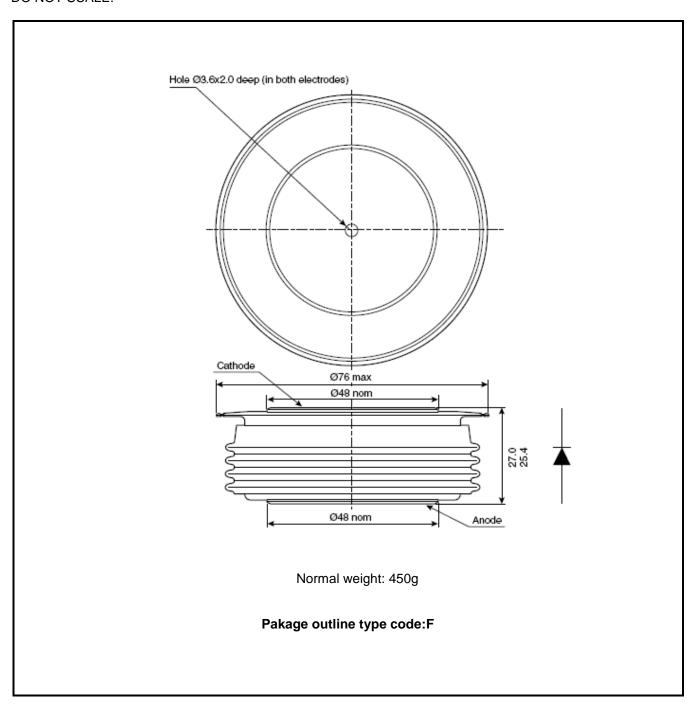


Fig.7 Maximum (limit) transient thermal impedancejunction to case



## **PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



## Note:

Some packages may be supplied with gate and or tags.



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